

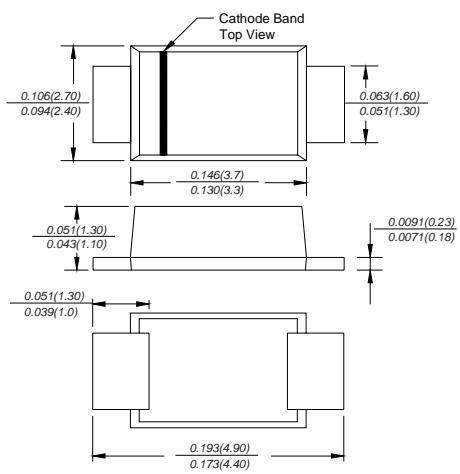


# SS12F THRU SS1200F

## SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

Reverse Voltage - 20 to 200 Volts   Forward Current - 1.0 Ampere

### SMAF



Dimensions in inches and (millimeters)

### FEATURES

- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- For surface mounted applications
- Metal silicon junction,majority carrier conduction
- Low power loss,high efficiency
- Built-in strain relief,ideal for automated placement
- High forward surge current capability
- High temperature soldering guaranteed: 260°C/10 seconds at terminals

### MECHANICAL DATA

**Case:** JEDEC SMAF molded plastic body

**Terminals:** leads solderable per MIL-STD-750, Method 2026

**Polarity:** Color band denotes cathode end

**Mounting Position:** Any

**Weight:** 0.0018 ounce, 0.064 grams

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz,resistive or inductive load,for capacitive load current derate by 20%.

MDD Catalog Number	SYMBOLS	SS12F	SS13F	SS14F	SS15F	SS16F	SS18F	SS110F	SS1150F	SS1200F	UNITS
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	20	30	40	50	60	80	100	150	200	VOLTS
Maximum RMS voltage	V <sub>RMS</sub>	14	21	28	35	42	56	70	105	140	VOLTS
Maximum DC blocking voltage	V <sub>Dc</sub>	20	30	40	50	60	80	100	150	200	VOLTS
Maximum average forward rectified current at T <sub>L</sub> (see fig.1)	I <sub>(AV)</sub>							1.0			Amp
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>							30.0			Amps
Maximum instantaneous forward voltage at 1.0A	V <sub>F</sub>		0.55		0.70		0.85		0.95		Volts
Maximum DC reverse current T <sub>A</sub> =25°C at rated DC blocking voltage T <sub>A</sub> =100°C	I <sub>R</sub>				0.5			0.2			mA
					10.0		5.0		2.0		
Typical junction capacitance (NOTE 1)	C <sub>J</sub>		110				90				pF
Typical thermal resistance (NOTE 2)	R <sub>θJA</sub>				88.0						°C/W
Operating junction temperature range	T <sub>J</sub>		-50 to +125				-50 to +150				°C
Storage temperature range	T <sub>STG</sub>				-50 to +150						°C

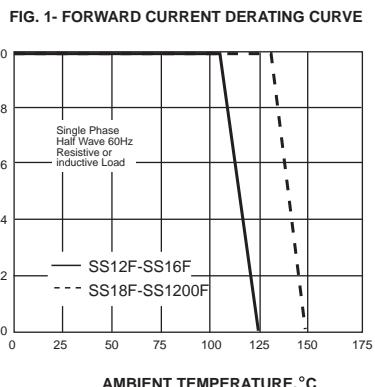
**Note:**1.Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2.P.C.B. mounted with 0.2x0.2" (5.0x5.0mm) copper pad areas

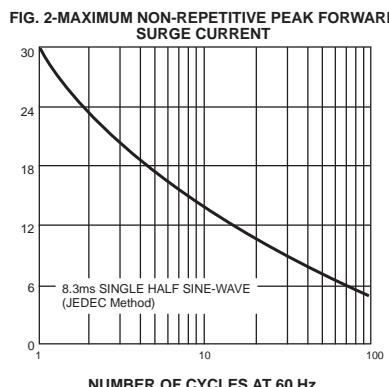


# RATINGS AND CHARACTERISTIC CURVES SS12F THRU SS1200F

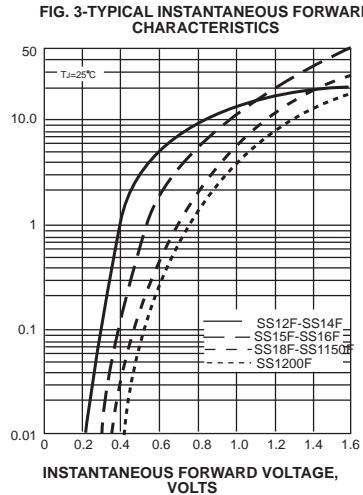
AVERAGE FORWARD RECTIFIED CURRENT,  
AMPERES



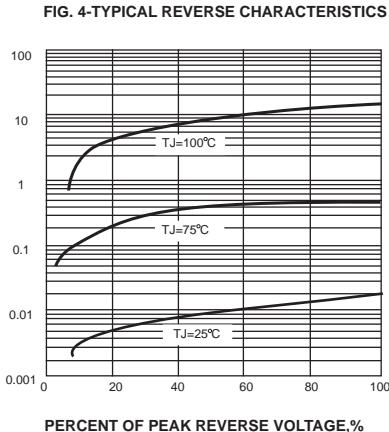
PEAK FORWARD SURGE CURRENT,  
AMPERES



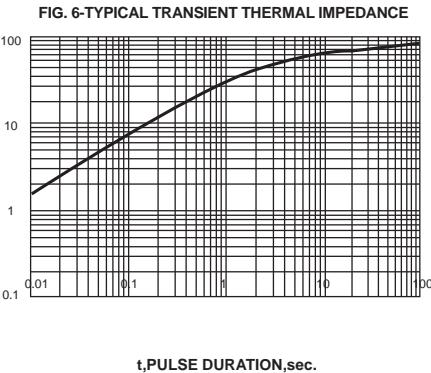
INSTANTANEOUS FORWARD  
CURRENT,AMPERES



INSTANTANEOUS REVERSE CURRENT,  
MILLIAMPERES



TRANSIENT THERMAL IMPEDANCE,  
°C/W



The curve graph is for reference only, can't be the basis for judgment(曲线图仅供参考)!



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